

S-89210/89220 Series

MINI ANALOG SERIES CMOS COMPARATOR

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Rev.4.0_01

The mini-analog series is a group of ICs that incorporate a general purpose analog circuit in a small package. The S-89210/89220 Series is a CMOS type comparator works on a lower voltage and lower current consumption. These features make this product the ideal solution for small battery-powered portable equipment. This product is a single comparator (with 1 circuit).

■ Features

• Lower operating voltage than the conventional general-purpose:

 V_{DD} = 1.8 V to 5.5 V

• Low current consumption: $I_{DD} = 50 \mu A \text{ Typ. (S-89210 Series)}$

 I_{DD} = 10 μ A Typ. (S-89220 Series)

• Low input offset voltage: 4.0 mV Max.

• Lead-free, halogen-free*1

*1. Refer to "■ Product Name Structure" for details.

■ Application

- · Mobile phones
- Notebook PCs
- · Digital cameras
- Digital video cameras

■ Package

• SC-88A

■ Block Diagram

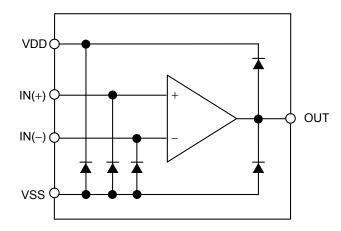
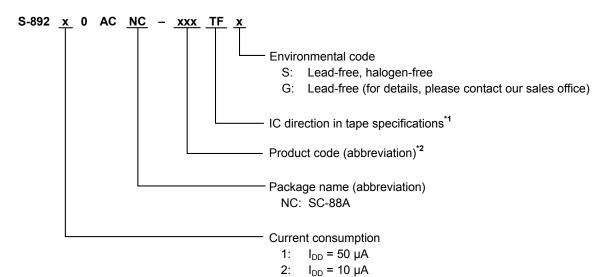


Figure 1

■ Product Name Structure

Users can select the product type for the S-89210/89220 Series. Refer to "1. **Product name**" regarding the contents of product name, "2. **Package**" regarding the package drawings and "3. **Product name list**" regarding the product type.

1. Product name



- *1. Refer to the tape specifications.
- *2. Refer to "3. Product name list".

2. Package

Package Name	Drawing Code						
	Package	Tape	Reel				
SC-88A	NP005-B-P-SD	NP005-B-C-SD	NP005-B-R-SD				

3. Product name list

Table 1

Product name	Current consumption	Rise propagation delay time*1	Fall propagation delay time*1		
S-89210ACNC-1C0TFz	50 μΑ	30 μs	6 μs		
S-89220ACNC-1C1TFz	10 μΑ	150 μs	30 μs		

^{*1.} The value when $V_{DD} = 3.0 \text{ V}$

Remark z: G or S

■ Pin Configuration

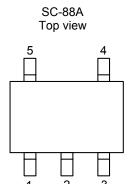


Figure 2

Table 2

Pin No.	Symbol	Description
1	IN(+)	Non-inverted input pin
2	VSS	GND pin
3	IN(-)	Inverted input pin
4	OUT	Output pin
5	VDD	Positive power supply pin

■ Absolute Maximum Ratings

Table 3

$T_2 = 1$	-25°€	unlace	otherwise	enacified)
(1a – 1	-20 0	uniess	Offici Mise	Specilledi

Parameter	Symbol	Absolute Maximum Ratings	Unit
Power supply voltage	V_{DD}	$V_{SS} - 0.3$ to $V_{SS} + 10.0$	V
Input voltage	VIN	$V_{SS} - 0.3$ to $V_{SS} + 7.0$	V
Output voltage	Vouт	$V_{SS} - 0.3$ to $V_{DD} + 0.3$	V
Differential input voltage	V _{IND}	±7.0	V
Output pin current	Isink	13	mA
Davier discipation	D	200 (When not mounted on board)	mW
Power dissipation	P _D	350* ¹	mW
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	T _{stg}	−55 to +125	°C

*1. When mounted on board

[Mounted board]

(1) Board size: 114.3 mm \times 76.2 mm \times t1.6 mm (2) Board name: JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

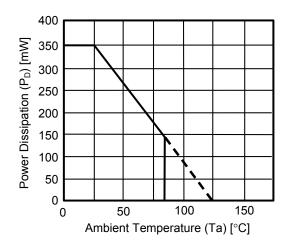


Figure 3 Power Dissipation of Package (When Mounted on Board)

■ Electrical Characteristics

Table 4

 $(Ta = +25^{\circ}C \text{ unless otherwise specified})$

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	Test Circuit
Range of operating power supply voltage	V_{DD}	_	1.8	-	5.5	٧	-

1. $V_{DD} = 5.0 \text{ V}$

Table 5

DO EL	Ot	0/ = 0 \ 0
DC FIECTRICAL	Characteristic	$(V_{DD} = 5 \cup V)$

(Ta = +25°C unless otherwise specified)

DC Liectrical Characteristic	V-0.0	- 3.0 V)					specifica	
Parameter	Symbol	C	Conditions	Min.	Тур.	Max.	Unit	Test Circuit
Current consumption		S-89210 Serie	S	_	50	120	μΑ	5
Current consumption	I _{DD}	S-89220 Serie	S	_	10	30	μΑ	5
Input offset voltage	V_{IO}		_	-4	±3	+4	mV	1
Input offset current	I _{IO}		_	_	1	1	pА	ı
Input bias current	I _{BIAS}		_	_	1	_	pА	1
Common-mode input voltage range	V _{CMR}		_	0	-	4.3	٧	2
Maximum output swing	V _{OH}	I _{OH} = 20 μA		4.7	1	-	V	3
voltage	V_{OL}	I_{OL} = 20 μ A		_	1	0.01	>	4
Common-mode input signal rejection ratio	CMRR		-	60	70	ı	dB	2
Power supply voltage rejection ratio	PSRR		_	60	70	ı	dB	1
Source current	1	\/ - 0 \/	S-89210 Series	120	1	_	μΑ	6
Source current	Isource	$V_{OUT} = 0 V$	S-89220 Series	25	1	_	μΑ	6
Sink current	I _{SINK}	$V_{OUT} = 0.5 V$	·	9	_	_	mΑ	7

Table 6

	1	,					,
Parameter	Symbol	Condition	Conditions			Max.	Unit
Rise propagation delay time	4		S-89210 Series	_	45	-	μs
	t PLH		S-89220 Series	_	230	1	μs
Call propagation delay time	4	Overdrive = 100 mV C_L = 15 pF (Refer to Figure 11)	S-89210 Series	_	9	1	μs
Fall propagation delay time	t PHL		S-89220 Series	_	45	_	μs
Rise response time	tтьн		S-89210 Series	_	3	_	μs
			S-89220 Series	_	15	_	μs
Fall response time	4		S-89210 Series	_	3	_	μs
	tthl		S-89220 Series	_	15		μs

8

Sink current

2. $V_{DD} = 3.0 \text{ V}$

Table 7

DC Electrical Characteristic	C Electrical Characteristic (V _{DD} = 3.0 V)					(Ta = +25°C unless otherwise specified)					
Parameter	Symbol	(Conditions	Min.	Тур.	Max.	Unit	Test Circuit			
Current consumption	1	S-89210 Serie	es	_	50	120	μΑ	5			
	IDD	S-89220 Serie	es	-	10	30	μΑ	5			
Input offset voltage	Vio		_	-4	±3	+4	mV	1			
Input offset current	lio		_	-	1	_	pА	ı			
Input bias current	I _{BIAS}		_	-	1	_	pА	-			
Common-mode input voltage range	V _{CMR}		-	0	-	2.3	V	2			
Maximum output swing	Vон	Іон = 20 μА		2.7	_	_	V	3			
voltage	Vol	I _{OL} = 20 μA		_	_	0.01	V	4			
Common-mode input signal rejection ratio	CMRR		-		70	_	dB	2			
Power supply voltage rejection ratio	PSRR	-		60	70	_	dB	1			
Sauras aumant		V - 0 V	S-89210 Series	120	_	_	μΑ	6			
Source current	Isource Vout = 0 V		S-89220 Series	25	_	_	μA	6			

Table 8

AC Flectrical	Characteristic	$(V_{DD} = 3.0 \text{ V})$
AC Electrical	Characteristic	(VDD - 3.U V)

Isink

 $V_{OUT} = 0.5 V$

(Ta = +25°C unless otherwise specified)

mΑ

7

		(1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.					
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Disc proposition delevitime			S-89210 Series	-	30	_	μs
Rise propagation delay time to	t _{PLH}		S-89220 Series	_	150	_	μs
Call propagation delay time	4	O	S-89210 Series	_	6	_	μs
Fall propagation delay time	t _{PHL}	IC∟ = 15 nF	S-89220 Series	_	30	_	μs
Rise response time	_		S-89210 Series	_	2	_	μs
	tтьн	(Neier to Figure 11)	S-89220 Series	_	10	_	μs
Fall response time	4		S-89210 Series	_	2	_	μs
	t _{THL}		S-89220 Series	_	10	_	μs

Isink

 $V_{OUT} = 0.5 V$

mΑ

7

μs

3. $V_{DD} = 1.8 \text{ V}$

Sink current

Table 9

DC Electrical Characteristic (V _{DD} = 1.8 V)				(Ta =	(Ta = +25°C unless otherwise specified)				
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit	Test Circuit	
Compant consumention		S-89210 Series		_	50	120	μΑ	5	
Current consumption	I _{DD}	S-89220 Series		_	10	30	μΑ	5	
Input offset voltage	Vio		_	-4	±3	+4	mV	1	
Input offset current	lio				1	_	рА	_	
Input bias current	I _{BIAS}			_	1	_	рА		
Common-mode input voltage range	V _{CMR}	_		0	_	1.1	V	2	
Maximum output swing	VoH	Іон = 20 μА		1.5		_	V	3	
voltage V _{OL}		I _{OL} = 20 μA		_	_	0.01	V	4	
Common-mode input signal rejection ratio	CMRR	-		60	70	_	dB	2	
Power supply voltage rejection ratio	PSRR	-		60	70	_	dB	1	
Source current	1	V - 0.V	S-89210 Series	100	_	_	μΑ	6	
	Isource Vo	V _{OUT} = 0 V	S-89220 Series	20	_	_	μA	6	

Table 10

5

S-89220 Series

AC Electrical Characteristic ($V_{DD} = 1.8 \text{ V}$) (Ta = +25°C unless otherwise speci						ecified)	
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Discourage states delevitimes			S-89210 Series	_	20	_	μs
Rise propagation delay time	t _{PLH}		S-89220 Series	_	100	_	μs
Fall propagation delay time	t _{PHL}	Overdrive = 100 mV $C_L = 15 \text{ pF}$ (Refer to Figure 11) S-89220 S-89220	S-89210 Series	_	5	_	μs
			S-89220 Series	_	25	-	μs
Rise response time	t _{TLH}		S-89210 Series	_	1.2	_	μs
			S-89220 Series	_	6	_	μs
Fall response time			S-89210 Series	_	1.2	_	μs
	t _{THL}		S-80220 Series		6		116

■ Test Circuit

1. Power supply voltage rejection ratio, input offset voltage

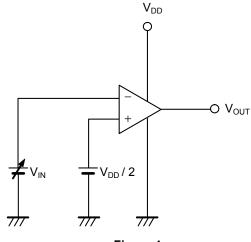


Figure 4

Power supply voltage rejection ratio (PSRR) Input offset voltage (V_{IO})

The input offset voltage (V_{IO}) is defined as V_{IN} - V_{DD} / 2 when V_{OUT} is changed by changing V_{IN} to V_{DD} / 2 level. The power supply voltage rejection ratio (PSRR) can be calculated by following expression, with the value of V_{IO} measured at each V_{DD}.

Test conditions:

When $V_{DD} = 1.8 \text{ V}$: $V_{DD} = V_{DD1}$, $V_{IO} = V_{IO1}$ When $V_{DD} = 5.0 \text{ V}$: $V_{DD} = V_{DD2}$, $V_{IO} = V_{IO2}$

$$PSRR = 20 \log \left(\left| \frac{V_{DD1} - V_{DD2}}{V_{IO1} - V_{IO2}} \right| \right)$$

2. Common-mode input signal rejection ratio, common-mode input voltage range

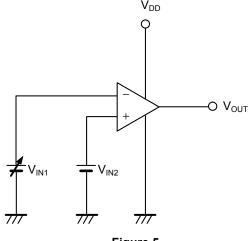


Figure 5

• Common-mode input signal rejection ratio (CMRR)

The common-mode input signal rejection ratio (CMRR) can be calculated by the following expression, with the offset voltage (V_{IO}) set as $V_{IN1} - V_{IN2}$ after V_{OUT} is changed by changing V_{IN1} .

Test conditions:

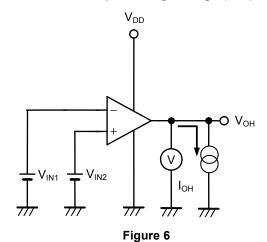
When $V_{IN2} = V_{CMR Max.}$: $V_{IN2} = V_{INH}$, $V_{IO} = V_{IO1}$ When $V_{IN2} = V_{DD} / 2$: $V_{IN2} = V_{INL}$, $V_{IO} = V_{IO2}$

$$CMRR = 20 log \left(\left| \frac{V_{INH} - V_{INL}}{V_{IO1} - V_{IO2}} \right| \right)$$

• Common-mode input voltage range (V_{CMR})

Varying V_{IN2} , the range of V_{IN2} that satisfies the common-mode input signal rejection ratio (CMRR) is the common-mode input voltage range (V_{CMR}).

3. Maximum output swing voltage (VoH)



• Maximum output swing voltage (Vон)

Test conditions: $V_{IN1} = \frac{V_{DD}}{2} - 0.5 \text{ V}$ $V_{IN2} = \frac{V_{DD}}{2} + 0.5 \text{ V}$ $I_{OH} = 20 \text{ } \mu\text{A}$

4. Maximum output swing voltage (Vol)

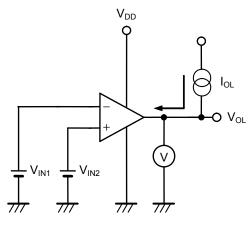


Figure 7

• Maximum output swing voltage (Vol)

Test conditions:
$$V_{IN1} = \frac{V_{DD}}{2} + 0.5 \text{ V}$$

$$V_{IN2} = \frac{V_{DD}}{2} - 0.5 \text{ V}$$

$$I_{OL} = 20 \text{ } \mu\text{A}$$

5. Current consumption

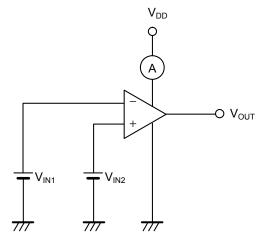


Figure 8

• Current consumption (IDD)

Test conditions:

 $V_{IN1} = V_{SS}$

 $V_{IN2} = V_{CMR\ Max.}$

6. Source current

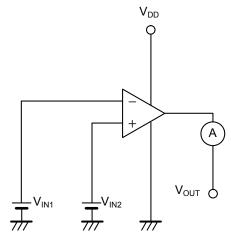


Figure 9

• Source current (Isource)

Test conditions:

$$V_{OUT} = 0 V$$

$$V_{IN1} = \frac{V_{DD}}{2} - 0.5$$

$$V_{IN1} = \frac{V_{DD}}{2} - 0.5 \text{ V}$$

$$V_{IN2} = \frac{V_{DD}}{2} + 0.5 \text{ V}$$

7. Sink current

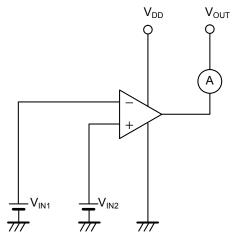


Figure 10

• Sink current (I_{SINK})

Test conditions:

$$V_{OUT} = 0.5 V$$

$$V_{IN1} = \frac{V_{DD}}{2} + 0.5 \, V$$

$$V_{OUT} = 0.5 \text{ V}$$

$$V_{IN1} = \frac{V_{DD}}{2} + 0.5 \text{ V}$$

$$V_{IN2} = \frac{V_{DD}}{2} - 0.5 \text{ V}$$

8. Propagation time, response time

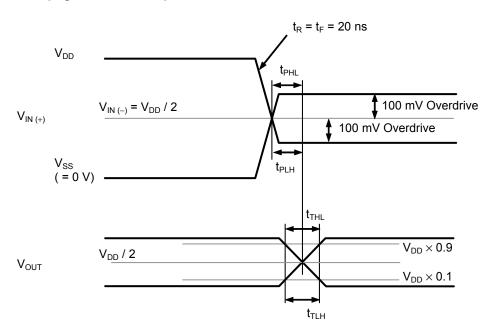


Figure 11

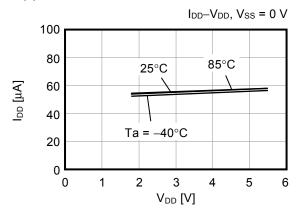
■ Precautions

- Do not apply an electrostatic discharge to this IC that exceeds performance ratings of the built-in electrostatic protection circuit.
- SII Semiconductor Corporation claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.
- Use this IC with the output pin current 13 mA or less.

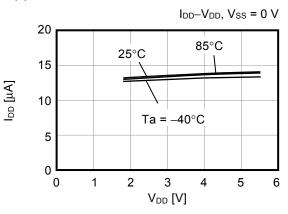
■ Characteristics (Typical Data)

1. Current consumption (IDD) vs. Power supply voltage (VDD)

(1) S-89210 Series



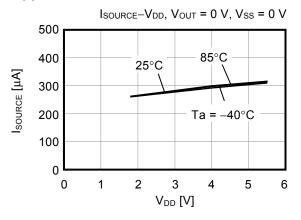
(2) S-89220 Series



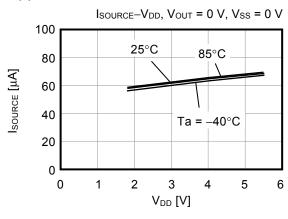
2. Output current characteristics

2. 1 Source current (I_{SOURCE}) vs. Power supply voltage (V_{DD})

(1) S-89210 Series

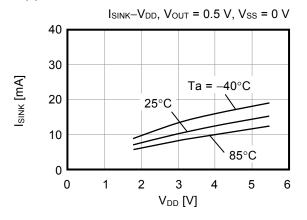


(2) S-89220 Series

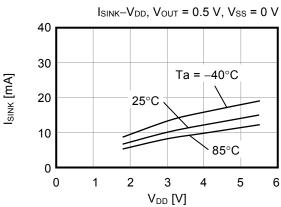


2. 2 Sink current (I_{SINK}) vs. Power supply voltage (V_{DD})

(1) S-89210 Series

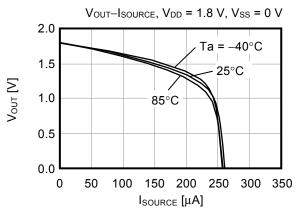


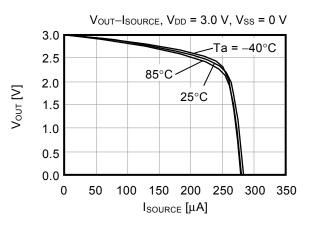
(2) S-89220 Series

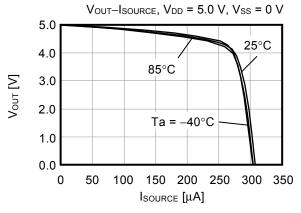


2. 3 Output voltage (Vout) vs. Source current (Isource)

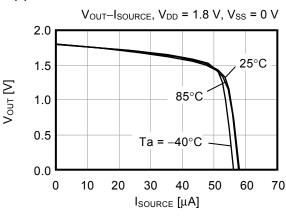
(1) S-89210 Series

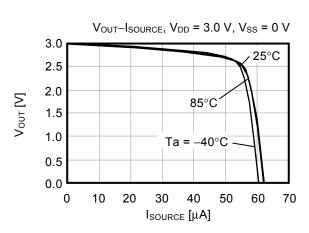


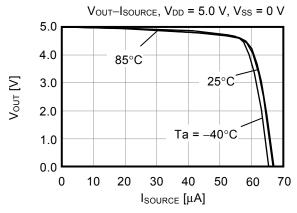




(2) S-89220 Series

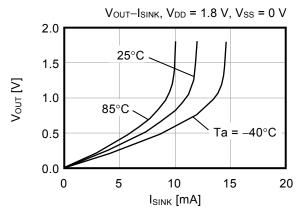


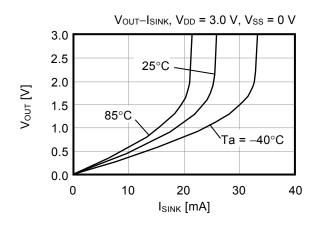


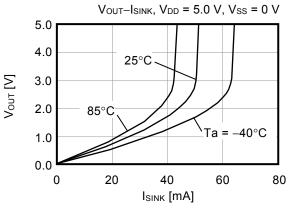


2. 4 Output voltage (Vout) vs. Sink current (ISINK)

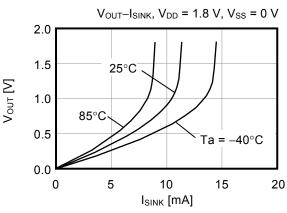
(1) S-89210 Series

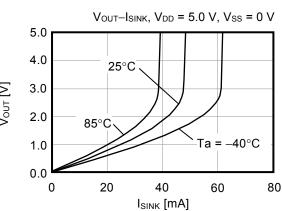


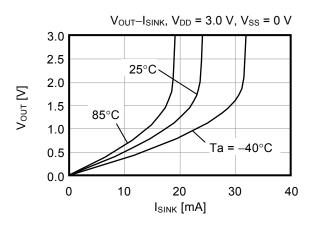


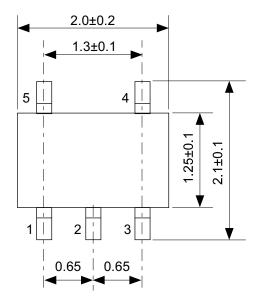


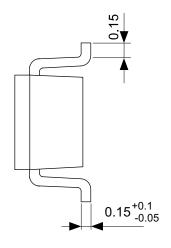
(2) S-89220 Series

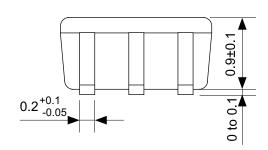








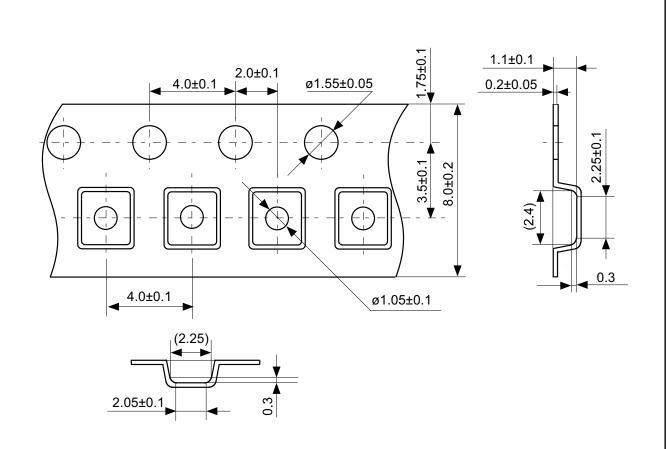


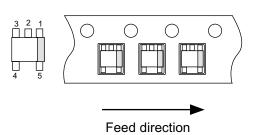


No. NP005-B-P-SD-1.1

TITLE	SC88A-B-PKG Dimensions			
No.	NP005-B-P-SD-1.1			
SCALE				
UNIT	mm			
SII Semiconductor Corporation				

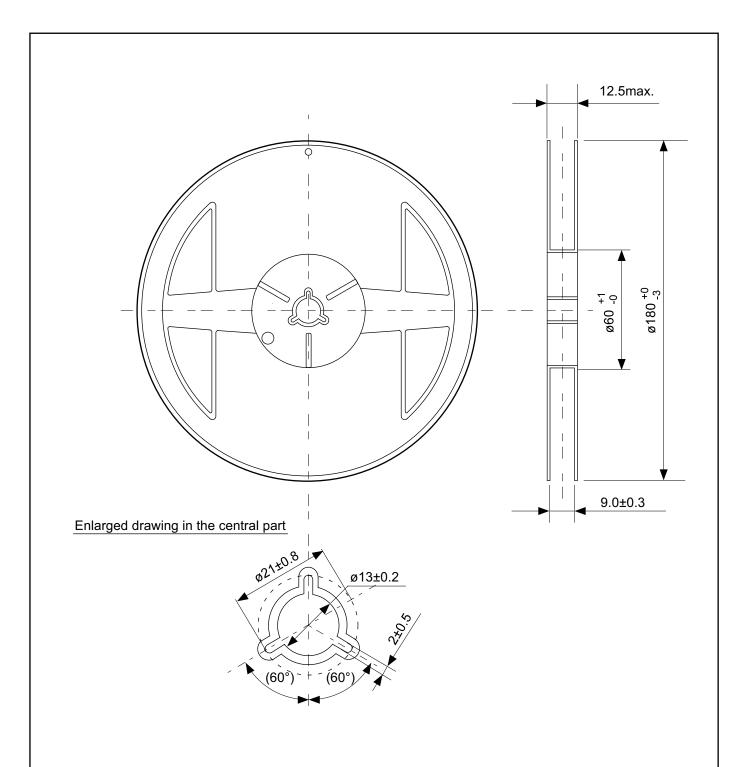
SII Semiconductor Corporation





No. NP005-B-C-SD-2.0

TITLE	SC88A-B-Carrier Tape			
No.	NP005-B-C-SD-2.0			
SCALE				
UNIT	mm			
SII Semiconductor Corporation				



No. NP005-B-R-SD-2.1

SC88A-B-Reel						
NP005-B-R-SD-2.1						
	QTY.	3000				
mm						
SII Semiconductor Corporation						
	MPC	NP005-B-R-SE QTY.				

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 - SII Semiconductor Corporation is not responsible for damages caused by unauthorized or unspecified use of our products.
- 9. Semiconductor products may fail or malfunction with some probability.
 - The user of these products should therefore take responsibility to give thorough consideration to safety design including redundancy, fire spread prevention measures, and malfunction prevention to prevent accidents causing injury or death, fires and social damage, etc. that may ensue from the products' failure or malfunction.
 - The entire system must be sufficiently evaluated and applied on customer's own responsibility.
- 10. The products described herein are not designed to be radiation-proof. The necessary radiation measures should be taken in the product design by the customer depending on the intended use.
- 11. The products described herein do not affect human health under normal use. However, they contain chemical substances and heavy metals and should therefore not be put in the mouth. The fracture surfaces of wafers and chips may be sharp. Take care when handling these with the bare hands to prevent injuries, etc.
- 12. When disposing of the products described herein, comply with the laws and ordinances of the country or region where they are used.
- 13. The information described herein contains copyright information and know-how of SII Semiconductor Corporation. The information described herein does not convey any license under any intellectual property rights or any other rights belonging to SII Semiconductor Corporation or a third party. Reproduction or copying of the information described herein for the purpose of disclosing it to a third-party without the express permission of SII Semiconductor Corporation is strictly prohibited.
- 14. For more details on the information described herein, contact our sales office.

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